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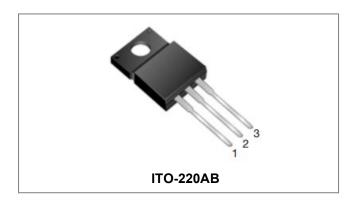


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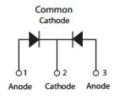
### MBRF2060CTL SCHOTTKY RECTIFIER



#### **Features**

- 125°C T<sub>J</sub> operation
- Center tap configuration
- · Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

### **Circuit Diagram**



#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	60	٧
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=80°C, rectangular wave form	10(Per Leg) 20(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	150	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition		Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@10A, Pulse, T <sub>J</sub> = 25 °C		0.69	V
Reverse Current (Per Leg)*	I <sub>R1</sub>	$I_{R1}$ @ $V_R$ = rated $V_{R}$ , $T_J$ = 25 °C		1.0	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25  ^{\circ}C, f_{SIG} = 1MHz$		400	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body		-	nH
Voltage Rate of Change	dv/dt	-	1	10,000	V/μs
RSM Isolation Voltage (t = 1.0 second, R. H. < =30%, T <sub>A</sub> = 25 °C)	V <sub>ISO</sub>	Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction.	-	4500	V
,		Clip mounting, the epoxy body is inside the heatsink.	-	3500	
		Screw mounting, the epoxy body is inside the heatsink.	-	1500	

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

<sup>•</sup> China - Germany - Korea - Singapore - United States •

http://www.smc-diodes.com - sales@ smc-diodes.com •



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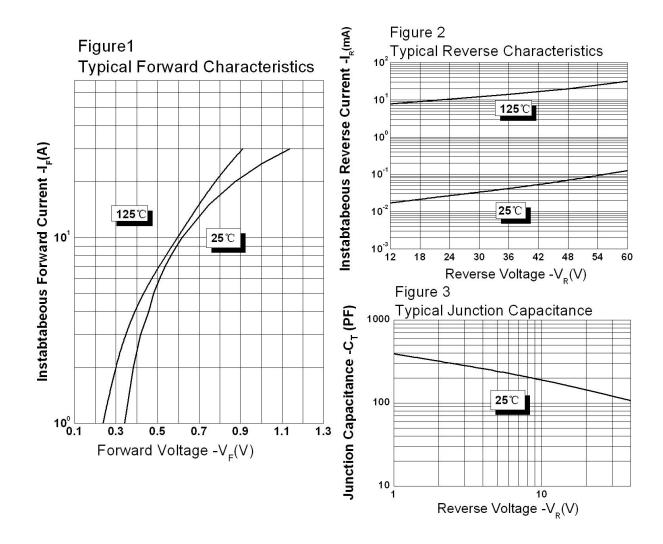




### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +125	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +125	°C
Typical Thermal Resistance Junction to Case	R <sub>0</sub> JC	DC operation	2.3	°C/W
Typical Thermal Resistance Case to Heat Sink	R <sub>0</sub> cs	Mounting surface, smooth and greased(only for TO-220)	0.50	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

### **Ratings and Characteristics Curves**



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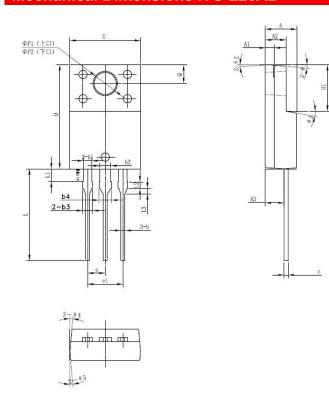


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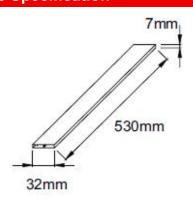


#### **Mechanical Dimensions ITO-220AB**



OVMBOL	Millimeters			
SYMBOL	MIN.	TYP.	MAX.	
Α	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
b3	1.20	1.30	1.45	
b4	1.60	1.70	1.85	
С	0.50	0.60	0.75	
D	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е		2.55		
e1		5.10		
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
L1	1.60	1.80	2.00	
L2	0.80	1.00	1.20	
L3	0.60	0.80	1.00	
ΦP1(上□)	3.30	3.50	3.70	
<b>ΦP2</b> (下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		

### **Tube Specification**



### **Marking Diagram**



Where XXXXX is YYWWL

 MBR
 = Device Type

 F
 = Package type

 20
 = Forward Current (20A)

 60
 = Reverse Voltage (60V)

 CTL
 = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

## **Ordering Information**

Device	Package	Shipping
MBRF2060CTL	ITO-220AB (Pb-Free)	50 pcs/ tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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#### MBRF2060CTL



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